



PJQ5453-AU

40V P-Channel Enhancement Mode MOSFET

Voltage

-40 V

Current

-16 A

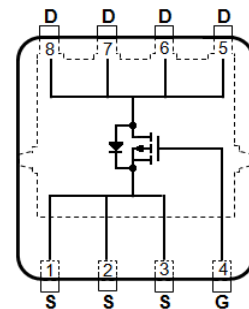
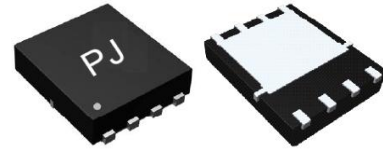
Features

- $R_{DS(ON)}$, $V_{GS}@-10V$, $I_D@-10A < 45m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_D@-5A < 68m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0028 ounces, 0.08 grams

DFN5060-8L



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	-40	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current (Note 4)	$T_C=25^\circ C$	I_D	-16	A
	$T_C=100^\circ C$		-10	
Pulsed Drain Current (Note 1)	$T_C=25^\circ C$	I_{DM}	-64	
Power Dissipation	$T_C=25^\circ C$	P_D	22	W
	$T_C=100^\circ C$		9	
Continuous Drain Current (Note 4)	$T_A=25^\circ C$	I_D	-5	A
	$T_A=70^\circ C$		-4	
Power Dissipation	$T_A=25^\circ C$	P_D	2	W
	$T_A=70^\circ C$		1.3	
Single Pulse Avalanche Energy (Note 6)		E_{AS}	31	mJ
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	$^\circ C$
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{\theta JC}$	5.7	$^\circ C/W$
	Junction to Ambient	$R_{\theta JA}$	62.5	

- Limited only By Maximum Junction Temperature



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Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-40	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.65	-2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-10A	-	37	45	mΩ
		V _{GS} =-4.5V, I _D =-5A	-	57	68	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-40V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic (Note 7)						
Total Gate Charge	Q _g	V _{DS} =-20V, I _D =-5A, V _{GS} =-4.5V (Note 2,3)	-	8.3	-	nC
Gate-Source Charge	Q _{gs}		-	2.6	-	
Gate-Drain Charge	Q _{gd}		-	2.7	-	
Input Capacitance	C _{iss}	V _{DS} =-15V, V _{GS} =0V, f=1MHZ	-	929	-	pF
Output Capacitance	C _{oss}		-	84	-	
Reverse Transfer Capacitance	C _{rss}		-	60	-	
Turn-On Delay Time	t _{d(on)}	V _{DS} =-20V, I _D =-1A, V _{GS} =-4.5V, R _G =6Ω (Note 2,3)	-	26	-	ns
Turn-On Rise Time	t _r		-	27	-	
Turn-Off Delay Time	t _{d(off)}		-	66	-	
Turn-Off Fall Time	t _f		-	40	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S	---	-	-	-16	A
Diode Forward Voltage	V _{SD}	I _S =-1A, V _{GS} =0V	-	-0.75	-1	V

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J=25°C.
4. The maximum current rating is package limited.
5. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
6. The test condition is L=0.1mH, I_{AS}=-25A, V_{DD}=-25V, V_{GS}=-10V, Starting T_J=25°C.
7. Guaranteed by design, not subject to production testing.



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TYPICAL CHARACTERISTIC CURVES

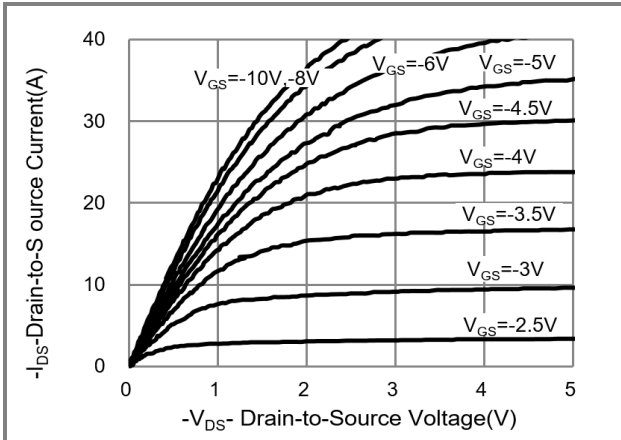


Fig.1 On-Region Characteristics

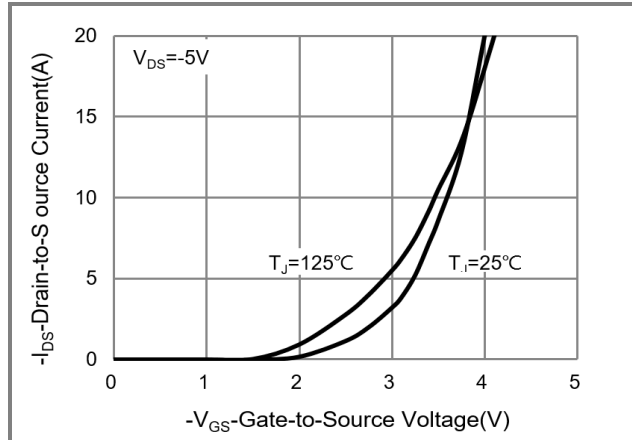


Fig.2 Transfer Characteristics

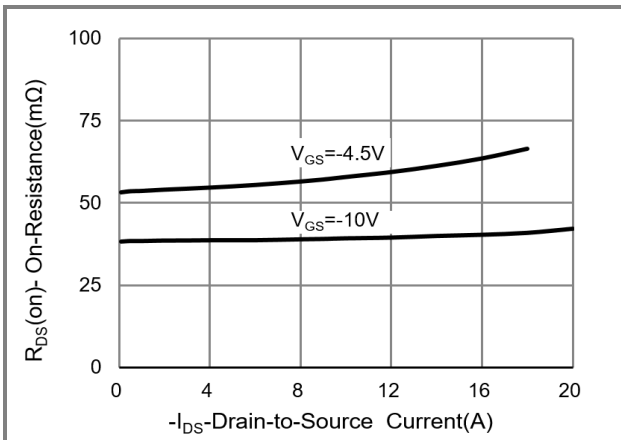


Fig.3 On-Resistance vs. Drain Current

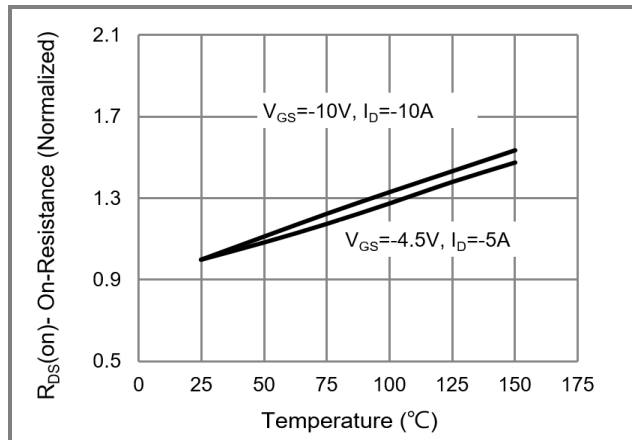


Fig.4 On-Resistance vs. Junction temperature

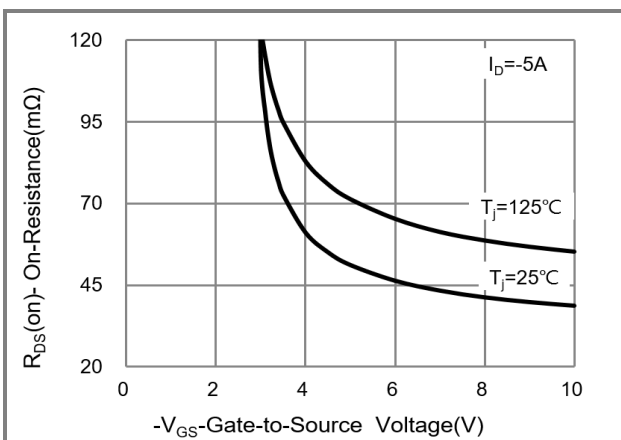


Fig.5 On-Resistance Variation with V_{GS}

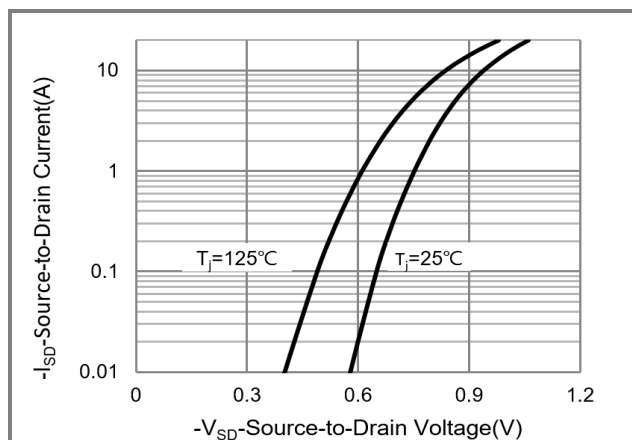


Fig.6 Body Diode Characteristics



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TYPICAL CHARACTERISTIC CURVES

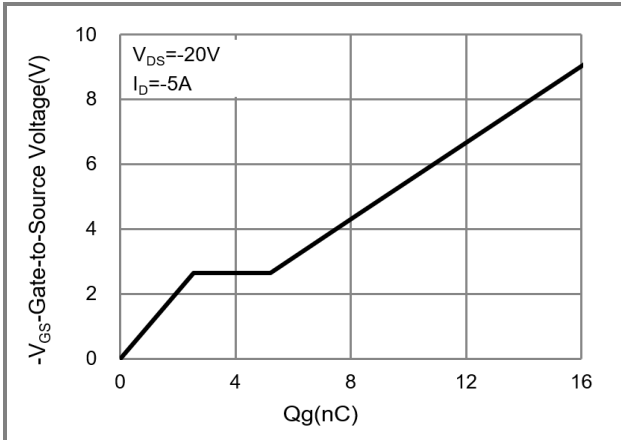


Fig.7 Gate-Charge Characteristics

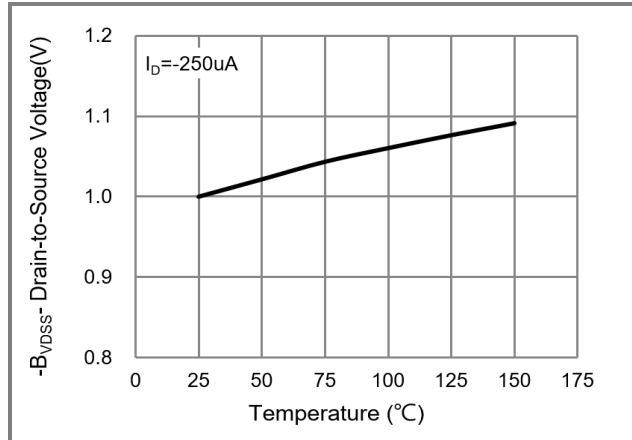


Fig.8 Breakdown Voltage Variation vs. Temperature

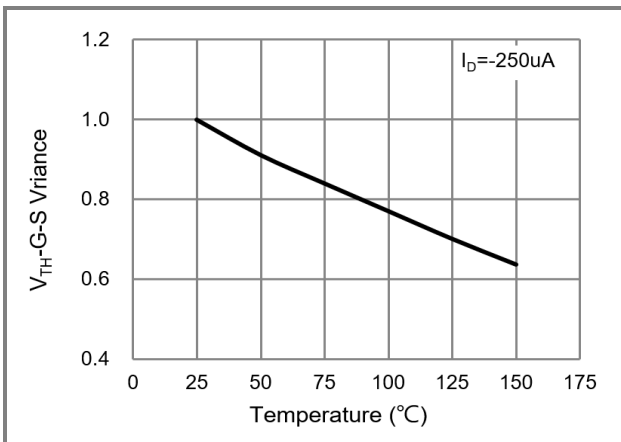


Fig.9 Threshold Voltage Variation with Temperature

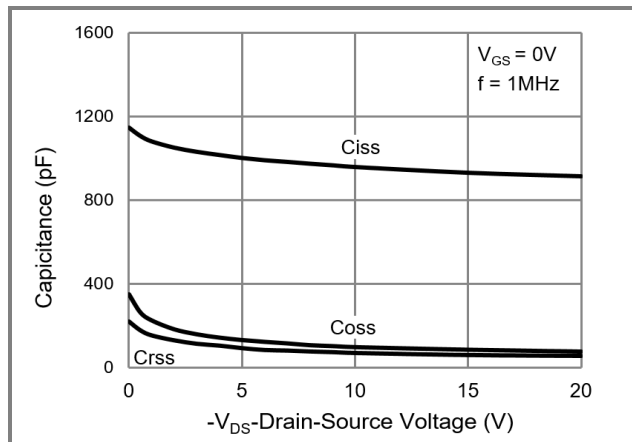


Fig.10 Capacitance vs. Drain-Source Voltage

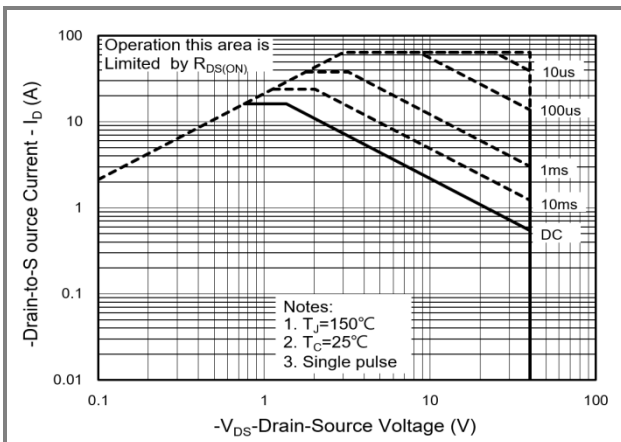


Fig.11 Maximum Safe Operating Area

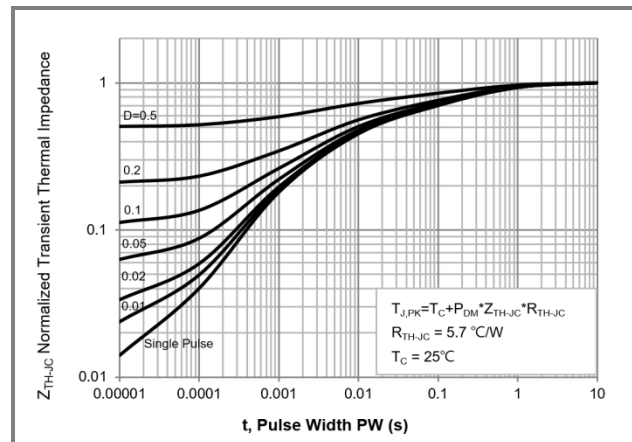


Fig.12 Normalized Thermal Transient Impedance

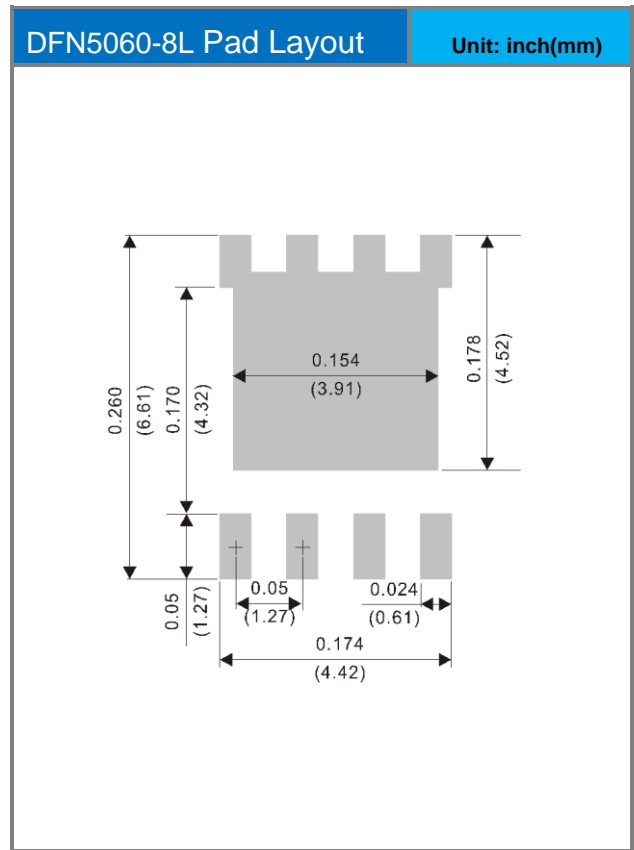
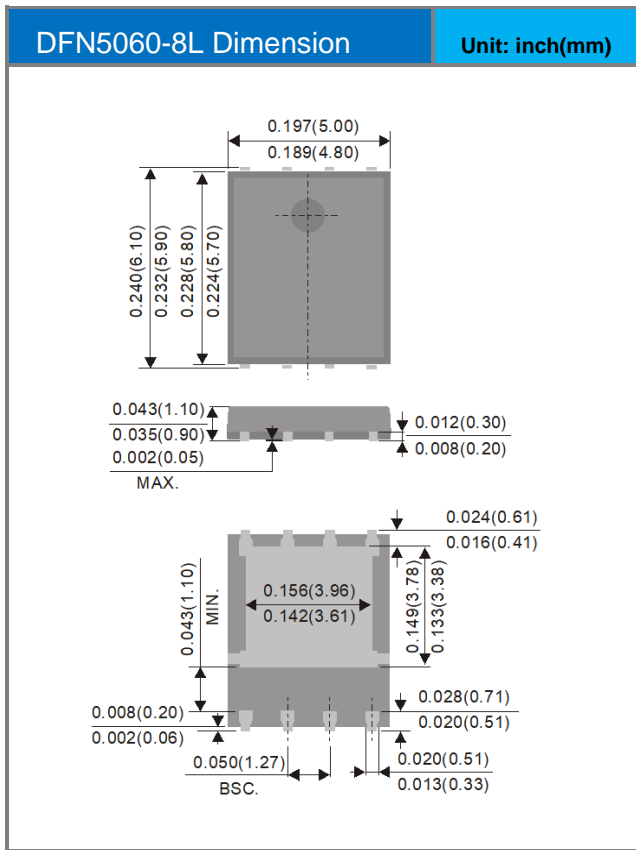


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Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ5453-AU_R2_000A1	DFN5060-8L	3000pcs / 13" reel	Q5453	Halogen free

Packaging Information & Mounting Pad Layout





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